F-8479

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(Rev. 7-80) Patent and Trademark Office 42-44F (F-49) INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)		Applicant: Holger ZELLMER, et al.						
		Filing Date:	Group: 2873					
	U.S. F	PATENT DOCUM	ENTS					
Examiner Initial	Document Number	Date	Name	Class	Subclass		g Date If priate	
1	US- 3,659,917	5/2/1972	Boutineau	359	245			
1	US- 4,379,620	4/12/1983	Erickson	359	249			
	US- 4,998,803	3/12/1991	Salour et al.	359	896			
#1	US- 4,301,362	11/17/1981	Mourou	250	214R			
	Document Number	Date	Country	Class	Subclass	Translation		
		N PATENT DOCI	Class	Subclass	Teanslation			
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		U.S.	PATENT DOCUM	AENTS					
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^C Concise	OTHER INI 9/15/1990 Physics 2/13/2000 NRC, Ya	elevance provided in specierence translated. O English FORMATION DISCLOSURE CITO Multikilowatt Pockels cell for pages 2589-2598 O RTP as a Q-switch for high residence of the page 2589-2598	fication. S Corsh abstract onl ATIONS (Including thigh average power petition rate appliance) 3-65 applications G.1	ncise statement of ry - copy of reference ng Author, Title, Date, ver laser systems L.F. ications E. Lebiush et	Pertinent P Weaver et : al. Electro-	n search rep provided in earch. lages, Etc.)	Applied	q	